

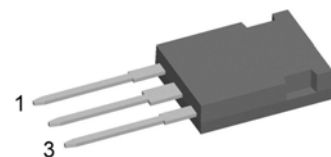
HiPerFRED²

$$\begin{aligned} V_{RRM} &= 300\text{ V} \\ I_{FAV} &= 2 \times 30\text{ A} \\ t_{rr} &= 35\text{ ns} \end{aligned}$$

High Performance Fast Recovery Diode
Low Loss and Soft Recovery
Common Cathode

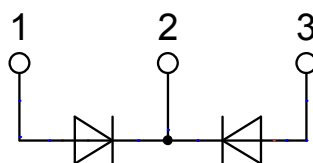
Part number

DPG60C300HJ



Backside: isolated

 E72873



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

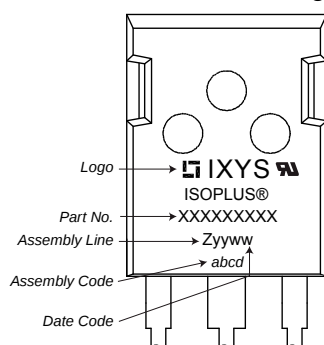
Package: ISOPLUS247

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Backside: DCB ceramic
- Reduced weight
- Advanced power cycling

Fast Diode				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse blocking voltage	T _{VJ} = 25°C				300	V
V _{RRM}	max. repetitive reverse blocking voltage	T _{VJ} = 25°C				300	V
I _R	reverse current, drain current	V _R = 300 V	T _{VJ} = 25°C			1	μA
		V _R = 300 V	T _{VJ} = 150°C			0.2	mA
V _F	forward voltage drop	I _F = 30 A	T _{VJ} = 25°C			1.26	V
		I _F = 60 A				1.54	V
		I _F = 30 A	T _{VJ} = 150°C			0.96	V
		I _F = 60 A				1.26	V
I _{FAV}	average forward current	T _C = 140°C rectangular d = 0.5	T _{VJ} = 175°C			30	A
V _{F0}	threshold voltage	} for power loss calculation only		T _{VJ} = 175°C		0.61	V
r _F	slope resistance					9.6	mΩ
R _{thJC}	thermal resistance junction to case					1.05	K/W
R _{thCH}	thermal resistance case to heatsink				0.25		K/W
P _{tot}	total power dissipation	T _C = 25°C				145	W
I _{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine; V _R = 0 V		T _{VJ} = 45°C		450	A
C _J	junction capacitance	V _R = 150 V f = 1 MHz		T _{VJ} = 25°C	60		pF
I _{RM}	max. reverse recovery current	} I _F = 30 A; V _R = 200 V -di _F /dt = 200 A/μs		T _{VJ} = 25°C	3		A
				T _{VJ} = 125°C	8.5		A
t _{rr}	reverse recovery time			T _{VJ} = 25°C	35		ns
				T _{VJ} = 125°C	65		ns

Package ISOPLUS247			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal ¹⁾			70	A
T_{VJ}	virtual junction temperature		-55		175	°C
T_{op}	operation temperature		-55		150	°C
T_{stg}	storage temperature		-55		150	°C
Weight				6		g
F_c	mounting force with clip		20		120	N
$d_{Spp/App}$	creepage distance on surface striking distance through air	terminal to terminal	2.7			mm
$d_{Spb/Abp}$		terminal to backside	4.1			mm
V_{ISOL}	isolation voltage	t = 1 second	3600			V
		t = 1 minute	3000			V

Product Marking



Part number

D = Diode
 P = HiPerFRED
 G = extreme fast
 60 = Current Rating [A]
 C = Common Cathode
 300 = Reverse Voltage [V]
 HJ = ISOPLUS247 (3)

Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DPG60C300HJ	DPG60C300HJ	Tube	30	505494

Similar Part	Package	Voltage class
DPG60C300HB	TO-247AD (3)	300
DPG60C300QB	TO-3P (3)	300
DPG60C300PC	TO-263AB (D2Pak) (2)	300
DPF60C300HB	TO-247AD (3)	300
DPG80C300HB	TO-247AD (3)	300

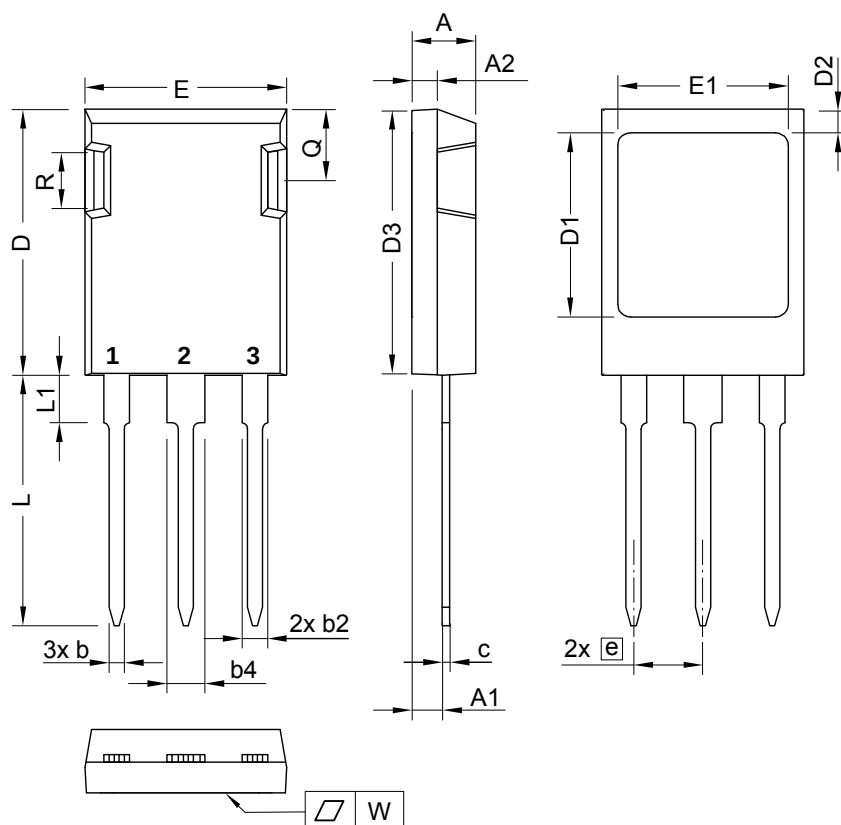
Equivalent Circuits for Simulation

* on die level

 $T_{VJ} = 175\text{ °C}$

$I \rightarrow$	V_0	R_0	Fast Diode	
$V_{0\text{ max}}$	threshold voltage	0.61		V
$R_{0\text{ max}}$	slope resistance *	7		mΩ

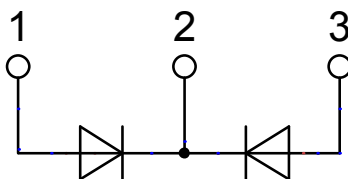
Outlines ISOPLUS247



Dim.	Millimeter		Inches	
	min	max	min	max
A	4.83	5.21	0.190	0.205
A1	2.29	2.54	0.090	0.100
A2	1.91	2.16	0.075	0.085
b	1.14	1.40	0.045	0.055
b2	1.91	2.20	0.075	0.087
b4	2.92	3.24	0.115	0.128
c	0.61	0.83	0.024	0.033
D	20.80	21.34	0.819	0.840
D1	15.75	16.26	0.620	0.640
D2	1.65	2.15	0.065	0.085
D3	20.30	20.70	0.799	0.815
E	15.75	16.13	0.620	0.635
E1	13.21	13.72	0.520	0.540
e	5.45 BSC		0.215 BSC	
L	19.81	20.60	0.780	0.811
L1	3.81	4.38	0.150	0.172
Q	5.59	6.20	0.220	0.244
R	4.25	5.50	0.167	0.217
W	-	0.10	-	0.004

Die konvexe Form des Substrates ist typ. < 0.04 mm über der Kunststoffoberfläche der Bauteilunterseite
 The convex bow of substrate is typ. < 0.04 mm over plastic surface level of device bottom side

Die Gehäuseabmessungen entsprechen dem Typ TO-247 AD gemäß JEDEC außer Schraubloch und L_{max} .
 This drawing will meet all dimensions requirement of JEDEC outline TO-247 AD except screw hole and except L_{max} .



Fast Diode

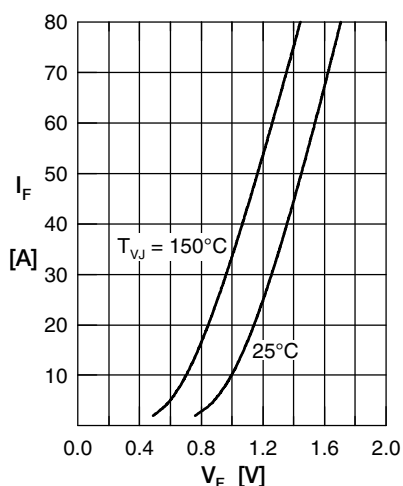


Fig. 1 Forward current I_F versus V_F

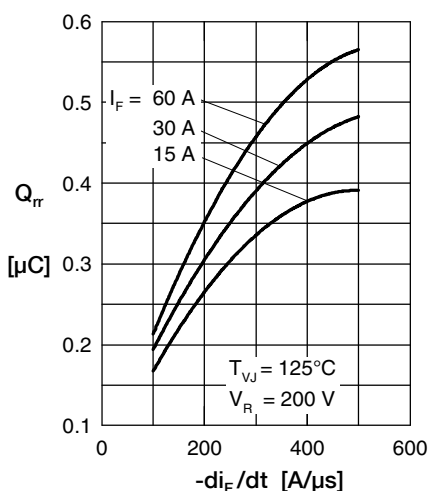


Fig. 2 Typ. reverse recov. charge Q_{rr} versus $-di_F/dt$

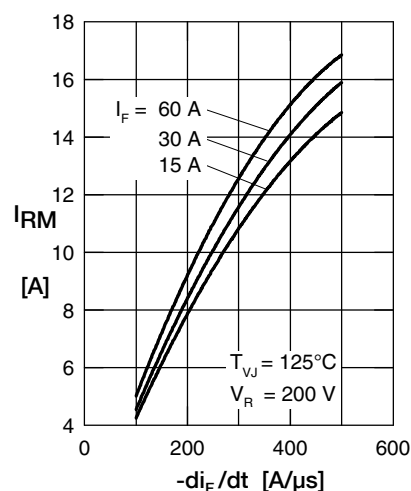


Fig. 3 Typ. reverse recov. current I_{RM} versus $-di_F/dt$

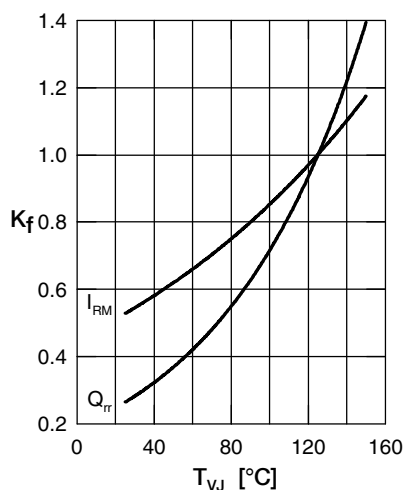


Fig. 4 Typ. dynamic parameters Q_{rr} , I_{RM} versus T_{VJ}

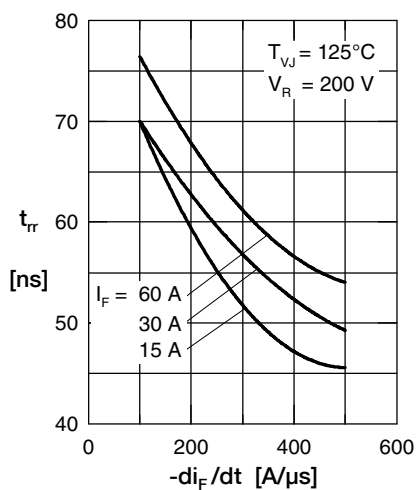


Fig. 5 Typ. reverse recov. time t_{rr} versus $-di_F/dt$

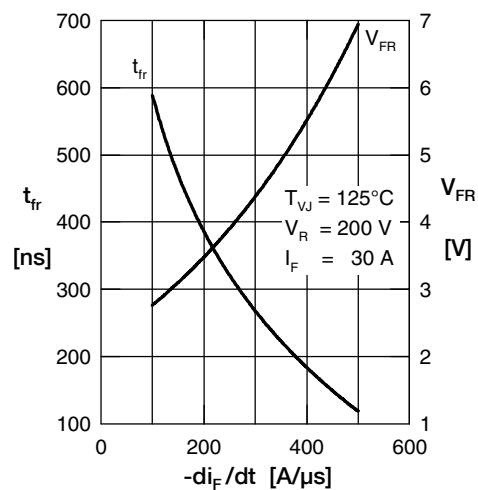


Fig. 6 Typ. forward recov. voltage V_{FR} & time t_{fr} versus di_F/dt

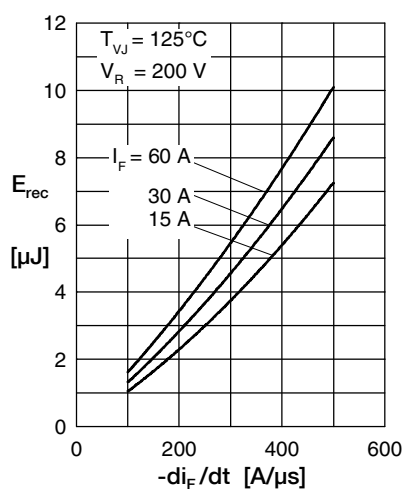


Fig. 7 Typ. recovery energy E_{rec} versus $-di_F/dt$

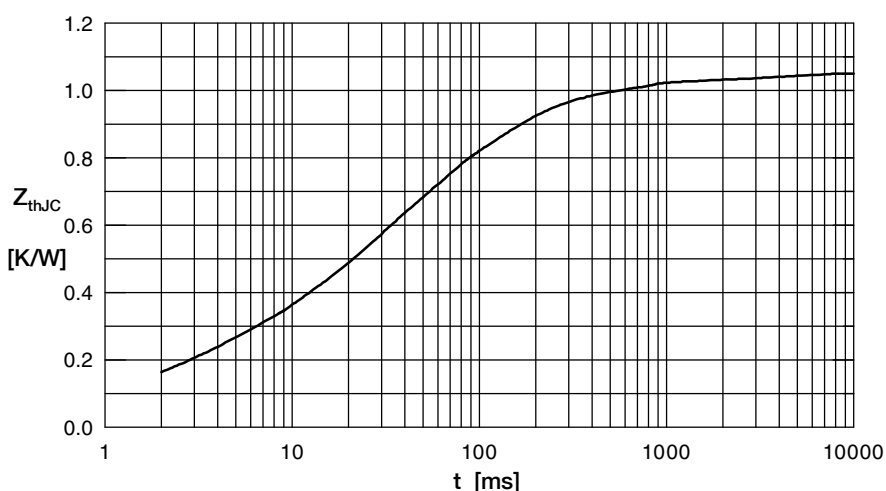


Fig. 8 Transient thermal impedance junction to case

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